MSKSEMI 美森科













ESD

VS

TSS

MOV

GDT

PIFD

MIC5504-X.XYM5-TR-MS

Product specification





GENERAL DESCRIPTION

The MIC5504-X.XYM5-TR-MS series are highly accurate, low noise, CMOS LDO Voltage Regulators. Of fering low output noise, high ripple rejection ratio, low dropout and very fast turn-on times, the MIC550 4-X.XYM5-TR-MS series is ideal for today's cutting edge mobile phone. Internally the MIC5504-X.XYM5-TR-MS includes a reference voltage source, error amplifiers, driver transistors, current limiters and phas e compensators.

The output voltage is set by current trimming. Voltages are selectable in 100mV steps within a range of 1.2V to 5.0V.

The MIC5504-X.XYM5-TR-MS series is also fully compatible with low ESR ceramic capacitors, reducing cost and improving output stability. This high level of output stability is maintained even during frequent load fluctuations, due to the excellent transient response performance and high PSRR achieved across a broad range of frequencies. The CE function allows the output of regulator to be turned off, resulting in greatly reduced power consumption.

FEATURES

- Low power consumption:40uA (Typ.)
- Low voltage drop:
- 0.12V@100mA@VOUT=3.3V(Typ.)
- Standby Mode: 1uA
- Low temperature coefficient
- High input voltage (up to 7V)
- Output voltage accuracy: tolerance ±2%
- SOT23-5 package

APPLICATIONS

- Battery-powered equipment
- Communication equipment
- Mobile phones
- Portable games
- Cameras, Video cameras
- Reference voltage sources

Pin Description and Marking

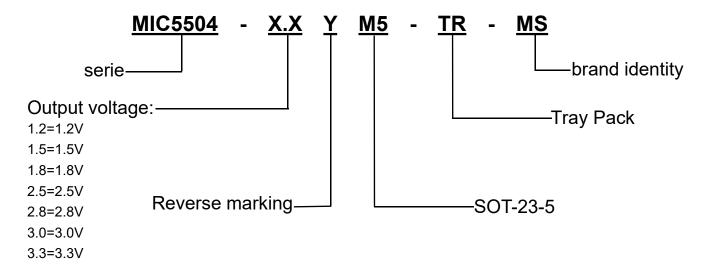
MIC5504-1.2YM 5-TR-MS	MIC5504-1.5YM 5-TR-MS	MIC5504-1.8YM 5-TR-MS	MIC5504-2.5YM 5-TR-MS	MIC5504-2.8YM 5-TR-MS	MIC5504-3.0YM 5-TR-MS	MIC5504-3.3YM 5-TR-MS
111	111		111			111
WX4	WXX	WXG	WXJ	WXM	WXP	wxs



PIN NUMBER	SYMBOL	FUNCTION	
1	V _{IN}	Power Input Pin	
2	GND	Ground	
3	CE	Chip Enable Pin	
4	NC	No Connection	
5	V _{out}	Output Pin	



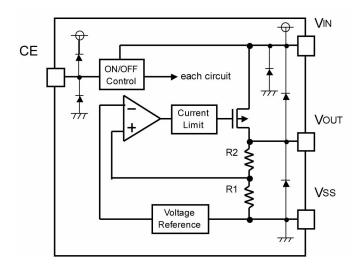
Ordering Information



Item number	package	Output voltage	MPQ
MIC5504-1.2YM5-TR-MS	SOT-23-5	1.2V	3000
MIC5504-1.5YM5-TR-MS	SOT-23-5	1.5V	3000
MIC5504-1.8YM5-TR-MS	SOT-23-5	1.8V	3000
MIC5504-2.5YM5-TR-MS	SOT-23-5	2.5V	3000
MIC5504-2.8YM5-TR-MS	SOT-23-5	2.8V	3000
MIC5504-3.0YM5-TR-MS	SOT-23-5	3.0V	3000
MIC5504-3.3YM5-TR-MS	SOT-23-5	3.3V	3000



Block Diagram



Absolute Maximum Ratings

Supply Voltage-0.3V to 8V Storage Temperature-50℃ to 125℃

Operating Temperature-40°C to 85°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

Symbol	Parameter	Max.	Unit
	Thermal Resistance (Junction to		
θ_{JA}	Ambient) (Assume no ambient	500	°C/W
	airflow, no heat sink)		
P _D	Power Dissipation	0.25	W

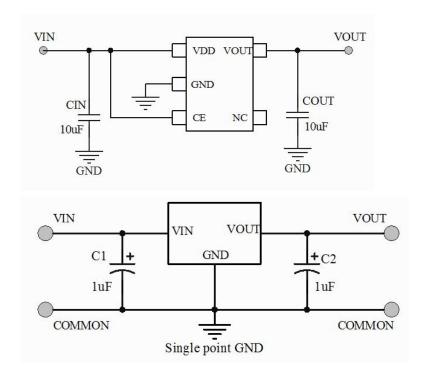
Note: P_D is measured at Ta= 25 $^{\circ}$ C



Electrical Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vout	Vin=Vout+1V 1.0mA≤Iout≤30mA	Vout×0.98	1	Vout×1.02	V
Output Current*1	lout	Vin-Vout=1V		350		mA
Line Regulation	riangleVout1/ $(riangle$ Vin·Vout)	4.3V≤Vin≤8V lout=10mA		0.05	0.2	%/V
Load Regulation	△Vout	Vin= 4.3V 1.0mA≤lout≤100mA		10	30	mV
Output voltage Temperature Coefficiency	△Vout/(Ta·Vout)	lout=30mA 0°C≤Ta≤70°C		±100		Ppm/ ℃
Supply Current	lss1			40		uA
Input Voltage	Vin				8	V
PSRR	PSRR	F=1KHz, Vin=4.3Vdc+1Vpp		60		dB

Typical Application Circuit





Operational Explanation

<Output Voltage Control>

The P-channel MOSFET is connected to the Vout pin, driven by the subsequent output signal. The output voltage at the Vout pin is controlled and stabilized by a system of negative feedback. The IC's internal circuitry can shut-down by the CE pin's signal <Low ESR Capacitors>

With the MIC5504-X.XYM5-TR-MS series, a stable output voltage is achievable even if used with low ESR capacitors as a phase compensation circuit is built-in. In order to ensure the effectiveness of the phase compensation, we suggest that an output capacitor (CL) is connected as close as possible to the output pin (Vout) and the GND pin. Please use an output capacitor with a capacitance value of at least 10uF. Also, please connect an input capacitor (CIN) of 10uF between the VIN pin and the GND pin in order to ensure a stable power input. Stable phase compensation may not be ensured if the capacitor runs out capacitance when depending on bias and temperature. In case the capacitor depends on the bias and temperature, please make sure the capacitor can ensure the actual

capacitance. <CE Pin>

The IC's internal circuitry can be shutdown via the signal from the CE pin with the MIC5504-X.XYM5-TR-MS series. The operational logic of the IC's CE pin is selectable (please refer to the selection guide). Although the CE pin is equal to an inverter input with CMOS hysteresis, with either the pull-up or pull-down options, the CE pin input current will increase when the IC is in operation. We suggest that you use this IC with either a VIN voltage or a Vss voltage input at the CE pin. If this IC is used with the correct specifications for the CE pin, the operational logic is fixed and the IC will operate normally. However, supply current may increase as a result of through current in the IC's internal circuitry.

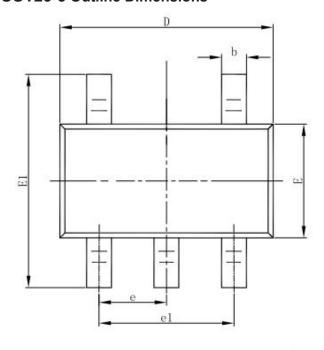
Notes on Use

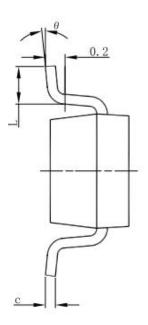
- 1. Please use this IC within the stated absolute maximum ratings. The IC is liable to malfunction should the ratings be exceeded.
- 2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between Vin and Vss wiring in particular.
- 3. Please wire the input capacitor (CIN) and the output capacitor (CL) as close to the IC as possible.

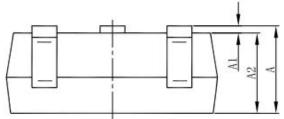


Packaging Information

SOT23-5 Outline Dimensions







Comb a I	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
Е	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)	0.037(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



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